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Inelastic cotunneling current and shot noise of an interacting quantum dot with ferromagnetic correlations

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We explore inelastic cotunneling through a strongly Coulomb-blockaded quantum dot attached to two ferromagnetic leads in the weak coupling limit using a generic quantum Langevin equation approach. We first develop a Bloch-type equation microscopically to describe the cotunneling-induced spin relaxation dynamics, and then develop explicit analytical expressions for the local magnetization, current, and its fluctuations. On this basis, we predict a novel zero-bias anomaly of the differential conductance in the absence of a magnetic field for the anti-parallel configuration, and asymmetric peak splitting in a magnetic field. Also, for the same system with large polarization, we find a negative zero-frequency differential shot noise in the low positive bias-voltage region. All these effects are ascribed to rapid spin-reversal due to underlying spin-flip cotunneling.

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I. INTRODUCTION

Recently, there has been extensive investigation of spin-dependent tunneling in nanoscale semiconductor devices coupled to ferromagnetic leads¹. It is well known that transport through a quantum dot (QD) includes two distinct mechanisms: sequential (first-order) tunneling if the QD level is in resonance with the Fermi levels of the electrodes, and higher-order tunneling (cotunneling) when the QD level is far removed from resonance, with sequential tunneling exponentially suppressed. Second-order cotunneling in the weak tunneling regime has already been experimentally observed at temperatures above the Kondo temperature². So far, most studies concerning spin-polarized tunneling through a QD have been focused on the sequential regime^{3,4} and on enhanced cotunneling in the strong tunneling regime, i.e. the Kondo-type transport^{5,6}. In particular, the theoretical prediction of Kondo peak-splitting in a quantum dot in the presence of parallel (P) spin-polarized leads⁵ has been confirmed in recent experiments⁶.

In this paper, we systematically analyze cotunneling through a strongly Coulomb-blockaded QD attached to two ferromagnetic leads in the weak tunneling regime at temperatures above the Kondo temperature. We develop an explicit expression for QD magnetization, which is believed to be of essential importance in understanding the nonequilibrium Kondo effect, albeit that the formula is derived in second-order perturbation theory^{7,8}. Our calculation of cotunneling current predicts a novel zero-bias peak (ZBP) of differential conductance in the absence of a magnetic field, and an asymmetric peak splitting in a magnetic field for the anti-parallel (AP) configuration. Our discussion shows that these interesting features arise from spin-flip processes which induce rapid spin-reversal. An analogous ZBP in cotunneling was found in an earlier work by Weymann⁹. Here our explicit analytic ex-

pressions show similar results of the peak height and its temperature dependence as in Ref. 9.

Moreover, we present an analytical investigation of zero-frequency shot noise in the cotunneling regime, which has been previously studied only in the sequential regime³. We predict that the differential shot noise at low bias-voltage region is heavily dependent on the polarization of electrodes in the AP configuration.

The remaining parts of the paper are arranged as follows. In Sec. II, we present the physical model and theoretical formulation used in this paper. We give the Bloch-type dynamical equations derived from a generic quantum Langevin equation approach^{10,11,12} to describe the time evolution of the QD spin and all relevant correlation functions. In Sec. III, we discuss the nonequilibrium magnetization of the QD in detail and point out that the spin-flip cotunneling will induce a rapid spin accumulation in the AP configuration. It is our main result for theoretical explanation of the novel behavior of the differential conductance and zero-frequency shot noise, whose explicit expressions are derived based on the linear response theory in Sec. IV. Numerical evaluations and elaborate discussions are also provided in this section. Finally, a brief conclusions are given in Sec. V.

II. THEORETICAL MODEL AND FORMULATION

Transport through an interacting QD with a single energy level ϵ_d connected to two ferromagnetic leads is modeled by a single impurity Anderson Hamiltonian. To describe *cotunneling* through the QD in the strongly Coulomb-blockaded regime (the on-site Coulomb interaction $U \rightarrow \infty$), in which the negative ϵ_d with $\epsilon_d \ll |\mu_\eta|$ (μ_η is the chemical potential in lead η and the symmetrically applied bias voltage V has $\mu_L = -\mu_R = eV/2$) is

satisfied, so that charge fluctuations are completely suppressed, we perform a mapping of the Anderson Hamiltonian onto the subspace with one electron in the dot by a Schrieffer-Wolff unitary transformation¹³, i.e. onto the effective Kondo Hamiltonian^{12,14}:

$$\begin{aligned} H &= H_0 + H_I, \\ H_0 &= \sum_{\eta\mathbf{k}\sigma} \varepsilon_{\eta\mathbf{k}} c_{\eta\mathbf{k}\sigma}^\dagger c_{\eta\mathbf{k}\sigma} - \Delta S^z, \\ H_I &= \sum_{\eta,\eta',\mathbf{k},\mathbf{k}'} J_{\eta\eta'} [(c_{\eta\mathbf{k}\uparrow}^\dagger c_{\eta'\mathbf{k}'\uparrow} - c_{\eta\mathbf{k}\downarrow}^\dagger c_{\eta'\mathbf{k}'\downarrow}) S^z \\ &\quad + c_{\eta\mathbf{k}\uparrow}^\dagger c_{\eta'\mathbf{k}'\downarrow} S^- + c_{\eta\mathbf{k}\downarrow}^\dagger c_{\eta'\mathbf{k}'\uparrow} S^+] + H_{\text{dir}}, \\ H_{\text{dir}} &= J_0 \sum_{\sigma} (c_{L\mathbf{k}\sigma}^\dagger + c_{R\mathbf{k}\sigma}^\dagger) (c_{L\mathbf{k}\sigma} + c_{R\mathbf{k}\sigma}), \end{aligned} \quad (1)$$

where $c_{\eta\mathbf{k}\sigma}^\dagger$ ($c_{\eta\mathbf{k}\sigma}$) is the creation (annihilation) operator for electrons with momentum $\mathbf{k}$, spin- σ and energy $\varepsilon_{\eta\mathbf{k}}$ in lead η ($= L, R$), $S^{z(\pm)}$ are Pauli spin operators of electrons in the QD, and $J_{\eta\eta'}$ is the Kondo exchange coupling constant. H_{dir} is the potential scattering term, which is decoupled from the electron spin due to the number of electrons in the dot level being one. As a result, this term has no influence on the dynamical evolution of the electron spin and behaves only as a direct bridge to connect the left and right leads and consequently to contribute a current being independent of the dynamics of the QD. For an Anderson model with symmetrical coupling to the leads t , we have $J_{\eta\eta'} = 2J_0 = t^2/\varepsilon_d$.

In this paper, we consider the ferromagnetism of the leads by means of a spin-dependent, flat density of states, $\rho_{\eta\sigma}$: $\rho_{L\uparrow} = \rho_{R\uparrow} = (1+p)\rho_0$; $\rho_{L\downarrow} = \rho_{R\downarrow} = (1-p)\rho_0$ for the P configuration, and $\rho_{L\uparrow} = \rho_{R\downarrow} = (1+p)\rho_0$; $\rho_{L\downarrow} = \rho_{R\uparrow} = (1-p)\rho_0$ for the AP configuration, with the degree of spin polarization p ($|p| \leq 1$) for both leads.

The spin-splitting, Δ , of the QD involves two contributions: an ambient magnetic-field B -induced Zeeman term, $\Delta_Z = g\mu_B B$ and an effective splitting, $\Delta_{\text{P(AP)}} = D \sum_{\eta} J_{\eta\eta} (\rho_{\eta\uparrow} - \rho_{\eta\downarrow}) = 2pD(J_{LL} \pm J_{RR})\rho_0$, caused by ferromagnetic correlations of the two leads (D is the band width of the leads). Based on this Hamiltonian, we find that (1) the differential conductance, dI/dV of the cotunneling current exhibits double peaks with width $2\Delta_p$ as a function of voltage, V , for P alignment of the lead magnetizations even without an ambient magnetic field; (2) the peak-splitting in the dI/dV vs. V curve without a magnetic field is also predicted for the AP configuration only with asymmetric couplings $J_{LL} \neq J_{RR}$, but it has a largely reduced width, $2\Delta_{\text{AP}}$, in comparison with the P case; (3) in both cases the splitting can be removed by properly tuning the direction and strength of the ambient magnetic field, to induce vanishing of the total spin-splitting Δ . These results provide a good qualitative explanation of the experimental findings in Ref. 6, and we can further clarify this issue in that the small but nonzero splitting found in the asymmetric AP case also stems from the lead-magnetization-induced spin-splitting in the QD.

We employ a generic Langevin equation approach to analyze this system in the weak cotunneling limit^{10,11,12}. In our derivation, operators of the QD spin and the reservoirs are first expressed formally by integration of their Heisenberg equations of motion (EOM), exactly to all orders of $J_{\eta\eta'}$. Next, under the assumption that the time scale of decay processes is much slower than that of free evolution, we replace the time-dependent operators involved in the integrals of these EOM's approximately in terms of their free evolutions. Thirdly, these EOM's are expanded in powers of $J_{\eta\eta'}$ up to second order. To this end, a Bloch-type dynamical equation is established to describe the time evolution of the QD spin variable as,

$$\dot{S}^z = -4C_{\text{P(AP)}}(\Delta) S^z + 2R_{\text{P(AP)}}(\Delta), \quad (2)$$

in which

$$\begin{aligned} C_{\text{P}}(\omega) &= \frac{\pi}{2} (g_{LL} + g_{RR}) (1-p^2) T \varphi\left(\frac{\omega}{T}\right) \\ &\quad + \frac{\pi}{2} g_{LR} (1-p^2) T \left[\varphi\left(\frac{\omega+V}{T}\right) + \varphi\left(\frac{\omega-V}{T}\right) \right], \end{aligned} \quad (3a)$$

$$R_{\text{P}}(\omega) = \frac{\pi}{2} (g_{LL} + g_{RR} + 2g_{LR}) (1-p^2) \omega, \quad (3b)$$

for the P configuration, and

$$\begin{aligned} C_{\text{AP}}(\omega) &= \frac{\pi}{2} (g_{LL} + g_{RR}) (1-p^2) T \varphi\left(\frac{\omega}{T}\right) + \frac{\pi}{2} g_{LR} T \\ &\quad \times \left[(1+p)^2 \varphi\left(\frac{\omega+V}{T}\right) + (1-p)^2 \varphi\left(\frac{\omega-V}{T}\right) \right], \end{aligned} \quad (4a)$$

$$\begin{aligned} R_{\text{AP}}(\omega) &= \frac{\pi}{2} (g_{LL} + g_{RR}) (1-p^2) \omega \\ &\quad + \pi g_{LR} (1+p^2) \omega + 2\pi g_{LR} p V, \end{aligned} \quad (4b)$$

for the AP configuration, with $g_{\eta\eta'} \equiv J_{\eta\eta'}^2 \rho_0^2$ and $\varphi(x) \equiv x \coth(x/2)$. Once again, we observe that the direct tunneling term has no contribution to dissipation of the QD spin variables. Throughout, we will use units with $\hbar = k_B = e = 1$.

Based on the dynamical equation, Eq. (2), we identify the cotunneling-induced spin relaxation rate as $1/T_1^{\text{P(AP)}} = 4C_{\text{P(AP)}}(\Delta)$, which stems completely from spin-flip events involving both single-barrier processes [Fig. 3(c)-(h) in Ref. 12] and double-barrier processes [i.e. electron-transferring (ET) processes] [Fig. 3(m)-(p) in Ref. 12]. For the case of fully spin-polarized leads ($p = \pm 1$) in the P alignment, cotunneling is unable to flip the electron spin in the QD, thus implying that there is no spin relaxation, i.e. $1/T_1^{\text{P}} = 0$ [$C(R)_{\text{P}} = 0$ at $p = \pm 1$ from Eq. (3a)]. For this case, we also have $\dot{S}^z = 0$, meaning that the QD spin orientation remains unchanged from its initial state. In contrast to this, in the case of fully AP spin-polarized leads, spin relaxation rate is nonzero and it arises solely from ET events [Fig. 1(c) and (d) below].

III. NONEQUILIBRIUM MAGNETIZATION

The nonequilibrium local magnetization, $S_{\text{P(AP)}}^{z\infty}$, of the QD in P(AP) configuration is readily obtained using the

steady-state solution of Eq. (2) as

$$S_P^{z\infty}(\Delta, V) = \frac{R_P(\Delta)}{2C_P(\Delta)} = \frac{\left(\frac{g_{LL} + g_{RR}}{2} + g_{LR}\right) \frac{\Delta}{T}}{(g_{LL} + g_{RR}) \varphi\left(\frac{\Delta}{T}\right) + g_{LR} \left[\varphi\left(\frac{\Delta + V}{T}\right) + \varphi\left(\frac{\Delta - V}{T}\right)\right]}, \quad (5)$$

$$S_{AP}^{z\infty}(\Delta, V) = \frac{R_{AP}(\Delta)}{2C_{AP}(\Delta)} = \frac{\frac{g_{LL} + g_{RR}}{2}(1 - p^2) \frac{\Delta}{T} + g_{LR}(1 + p^2) \frac{\Delta}{T} + 2g_{LR}p \frac{V}{T}}{(g_{LL} + g_{RR})(1 - p^2) \varphi\left(\frac{\Delta}{T}\right) + g_{LR} \left[(1 + p)^2 \varphi\left(\frac{\Delta + V}{T}\right) + (1 - p)^2 \varphi\left(\frac{\Delta - V}{T}\right)\right]}. \quad (6)$$

The P magnetization formula, Eq. (5), is identical with previous theoretical results for normal leads^{7,8,12}, and it is worth noting that the polarization of the reservoirs is fully reflected in the effective spin-splitting, Δ_P . If an ambient magnetic field is applied to induce vanishing of the spin-splitting, $\Delta = 0$, we have $S_P^{z\infty}(0, V) = 0$.

However, the local magnetization in the AP configuration is significantly different. Our calculated results are shown as functions of bias-voltage in Fig. 1. The relevant parameters in our calculations are: $g_{LL} = g_{RR} = g_{LR} = g = 0.25 \times 10^{-2}$; $D = 10$ (corresponding to Kondo temperature $T_K = 4.5 \times 10^{-5}D$ and $\Delta_P = 0.2pD$), and the temperature is $T/D = 0.002$. In the absence of an external magnetic field, $S_{AP}^{z\infty}$ is a two-valued function, $\pm p/(1 + p^2)$ if $|V|/T \gg 1$, and zero net spin of the QD occurs only at $V = 0$ when $p \neq 0$ [Fig. 1(a)]. Nonzero local spin is generated by the application of a bias-voltage, indicating spin accumulation in the QD under nonequilibrium conditions, and its orientation is rapidly flipped when the direction of the bias-voltage is reversed. This interesting behavior can be physically explained by *spin-flip elastic cotunneling* processes, as shown in Figs. 1(c) and (d). If $V > 0$ [Fig. 1(c)], the dominant cotunneling process is: first a spin-down electron in the QD tunnels out to the right lead, then a spin-up majority electron successively enters into the QD. This process continually pumps spin-down electrons out of the QD, while injecting spin-up electrons into the QD, giving rise to an up-spin pileup, until a steady-state is reached. On the contrary, for $V < 0$, the reverse process takes place, causing a down-spin accumulation [Fig. 1(d)]. Another interesting consequence of this spin-flip cotunneling is the appearance of a sharp peak at $V = 0$ in the $\frac{\partial S^z}{\partial V}$ vs. V curves, which leads to a novel ZBP in differential conductance for the AP configuration, as shown in Fig. 2(b). Simple calculation shows that the peak height of $\frac{\partial S^z}{\partial V}$ at $V = 0$ is proportional to the polarization p of electrodes, but is inversely proportional to the temperature T :

$$\left. \frac{\partial S_{AP}^z}{\partial V} \right|_{V \rightarrow 0} = \frac{p}{4T}. \quad (7)$$

While for $|V|/T \rightarrow \infty$, we have $\frac{\partial S_{AP}^z}{\partial V} = 0$. These two relations are useful in analyzing ZBP height of differential conductance. The temperature behavior of $\frac{\partial S^z}{\partial V}$ is shown schematically in Fig. 3(a) in the following section.

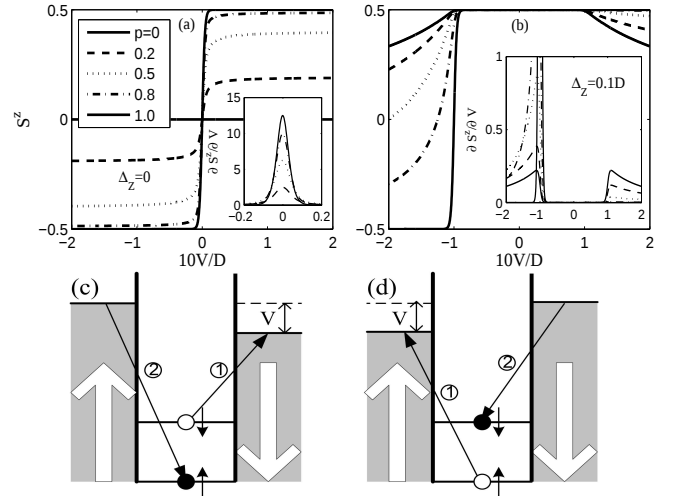


FIG. 1: Nonequilibrium QD magnetization, S^z , vs. bias-voltage, V , for the AP configuration at (a) $\Delta_z = 0$, and (b) $\Delta_z \neq 0$. Insets: $\frac{\partial S^z}{\partial V}$ vs. V curves. (c) and (d) ET spin-flip cotunneling processes.

A finite ambient magnetic field splits the peak in $\frac{\partial S^z}{\partial V}$ into two peaks at $V = \pm \Delta$ with unequal heights [Fig. 1(b)]. This occurs because spin-flip cotunneling becomes an energy-consuming (*inelastic*) process in a nonzero magnetic field, thus requiring a sufficiently strong external bias-voltage for activation. According to Eq. (6), the spin-reversal takes place approximately at $\Delta/V = -p$. Moreover, the application of a positive magnetic field makes the cotunneling shown in Fig. 1(c) prevail over that in Fig. 1(d). Correspondingly, the peak at $V = \Delta$ is suppressed, but the peak at $V = -\Delta$ is significantly enhanced if $p > 0$. The spin reversal property discussed above has potential for application in quantum computing and quantum information process-

ing. Finally, in the absence of a bias voltage, the local magnetization reduces to the equilibrium expression $S_{\text{P(AP)}}^{z\infty}(\Delta, 0) = \frac{1}{2} \tanh(\Delta/2T)$.

IV. CURRENT AND SHOT NOISE

The tunneling current operator of the QD is defined as the time rate of change of charge density $N_\eta = \sum_{\mathbf{k}\sigma} c_{\eta\mathbf{k}\sigma}^\dagger c_{\eta\mathbf{k}\sigma}$ in lead η : $J_\eta(t) = \dot{N}_\eta$. From linear-response theory we have

$$I = \langle J_\eta(t) \rangle = -i \int_{-\infty}^t dt' \langle [J_\eta(t), H_I(t')]_- \rangle_0, \quad (8)$$

where the statistical average $\langle \dots \rangle_0$ is performed with respect to two decoupled subsystems, QD and reservoirs.

Nonequilibrium quantum shot noise is another active subject in mesoscopic physics, because the current correlation function can provide further information about electronic correlations which is not available from conductance probes alone^{15,16}. The noise spectrum is defined as the Fourier transform of the current-current correlation function, $S_{\eta\eta'}(\tau)$, and it too can be calculated using linear-response theory:

$$S_{\eta\eta'}(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \frac{1}{2} \langle [\delta J_\eta(t), \delta J_{\eta'}(t')]_+ \rangle_0, \quad (9)$$

with $\delta J_\eta(t) = J_\eta(t) - \langle J_\eta(t) \rangle$.

Considering that the interaction Hamiltonian H_I in Eq. (1) contains two components, the direct tunneling term H_{dir} (the direct tunneling channel) and the cotunneling term (the indirect tunneling channel), we can divide the current and shot noise into three contributions,

$$I = I^0 + I^d + I^{\text{in}}, \quad (10a)$$

$$S_{LL}(\omega) = S_{LL}^0(\omega) + S_{LL}^d(\omega) + S_{LL}^{\text{in}}(\omega), \quad (10b)$$

due to the indirect channel, direct channel, and the interference effect between the two channels, respectively. After lengthy but straightforward calculations, we obtained explicit expressions for steady-state cotunneling current and for frequency-independent auto-correlation shot noise via the indirect channel:

$$I_{\text{P}}^0/\pi g_{LR} = (1+p^2)V + 2(1-p^2)V + 2TS_{\text{P}}^{z\infty} \times (1-p^2) \left[\varphi\left(\frac{V-\Delta}{T}\right) - \varphi\left(\frac{V+\Delta}{T}\right) \right], \quad (11a)$$

$$S_{LL}^{\text{P},0}(0)/\pi g_{LR} = (1+p^2)T\varphi\left(\frac{V}{T}\right) + (1-p^2)T \times \left[\varphi\left(\frac{V-\Delta}{T}\right) + \varphi\left(\frac{V+\Delta}{T}\right) \right] - 4S_{\text{P}}^{z\infty}(1-p^2)\Delta, \quad (11b)$$

for the P configuration, and

$$I_{\text{AP}}^0/\pi g_{LR} = (1-p^2)V + [(1-p)^2(V-\Delta) + (1+p)^2(V+\Delta)] + 2TS_{\text{AP}}^{z\infty}$$

$$\times \left[(1-p)^2\varphi\left(\frac{V-\Delta}{T}\right) - (1+p)^2\varphi\left(\frac{V+\Delta}{T}\right) \right], \quad (12a)$$

$$S_{LL}^{\text{AP},0}(0)/\pi g_{LR} = (1-p^2)T\varphi\left(\frac{V}{T}\right) + T \left[(1-p)^2\varphi\left(\frac{V-\Delta}{T}\right) + (1+p)^2\varphi\left(\frac{V+\Delta}{T}\right) \right] + 2S_{\text{AP}}^{z\infty}[(1-p)^2(V-\Delta) - (1+p)^2(V+\Delta)], \quad (12b)$$

for the AP configuration. Further elaborate analyses clarify that the first linearly bias-voltage-dependent terms in Eqs. (11) and (12) result from spin-conservative ET cotunneling processes, whereas spin-flip ET events are responsible for the other contributions¹². It is noteworthy that the first terms on the right hand sides of Eq. (11a) [(12a)] and Eq. (12a) [(12b)] obey the nonequilibrium fluctuation-dissipation (NFD) relation, while the other two terms represent the generalized NFD relation due to energy-consumption cotunneling processes¹⁷. The direct tunneling yields¹⁸:

$$I_{\text{P}}^d/\pi g_{LR} = 4\frac{g_0}{g_{LR}}(1+p^2)V, \quad (13a)$$

$$S_{LL}^{\text{P},d}(0)/\pi g_{LR} = 4\frac{g_0}{g_{LR}}(1+p^2)T\varphi\left(\frac{V}{T}\right), \quad (13b)$$

for the P configuration, and

$$I_{\text{AP}}^d/\pi g_{LR} = 4\frac{g_0}{g_{LR}}(1-p^2)V, \quad (14a)$$

$$S_{LL}^{\text{AP},d}(0)/\pi g_{LR} = 4\frac{g_0}{g_{LR}}(1-p^2)T\varphi\left(\frac{V}{T}\right), \quad (14b)$$

for the AP configuration with $g_0 = J_0^2\rho_0^2 = g_{LR}/4$. Because the direct tunneling is a spin-conservative process, it only interfere with the non-spin-flip cotunneling processes. The interference effect thus contributes to the current and shot noise only for the P configuration:

$$I_{\text{P}}^{\text{in}}/\pi g_{LR} = 16\sqrt{\frac{g_0}{g_{LR}}}pS_{\text{P}}^{z\infty}V, \quad (15a)$$

$$S_{LL}^{\text{P},\text{in}}(0)/\pi g_{LR} = 16\sqrt{\frac{g_0}{g_{LR}}}pS_{\text{P}}^{z\infty}T\varphi\left(\frac{V}{T}\right). \quad (15b)$$

Setting $p = 0$, we obtain the cotunneling current formula for the normal-lead/QD/normal-lead system [Eq. (36) in Ref. 12]¹⁹, and the corresponding frequency-independent shot noise $S_{LL}(0)$ is given by $[S^{z\infty} = S_{\text{P}}^{z\infty}]$:

$$S_{LL}(0)/\pi g_{LR} = 2T\varphi\left(\frac{V}{T}\right) - 4S^{z\infty}\Delta + T \left[\varphi\left(\frac{V-\Delta}{T}\right) + \varphi\left(\frac{V+\Delta}{T}\right) \right]. \quad (16)$$

We plot the differential conductance, $G_{\text{P(AP)}} = \frac{dI_{\text{P(AP)}}}{dV}$ (in units of $4\pi g$), and the tunnel magnetoresistance, $\text{TMR} = (G_{\text{P}} - G_{\text{AP}})/G_{\text{AP}}$, vs. bias-voltage in Fig. 2. For the P alignment, we find a characteristic jump at $V = \pm\Delta$ even at zero ambient magnetic field, $\Delta_Z = 0$, due to the lead polarization-induced spin-splitting, Δ_{P} . But for spin-polarized leads with larger polarization,

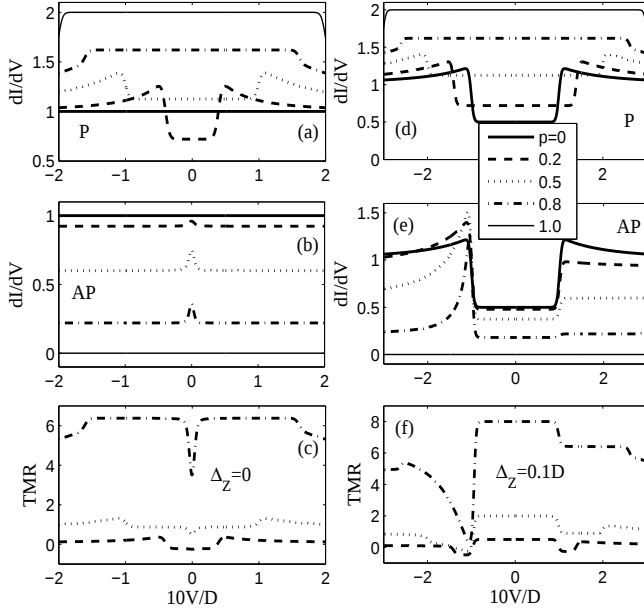


FIG. 2: Differential conductances and TMRs as functions of bias-voltage under zero (a)-(c) and nonzero (d)-(f) external magnetic fields for various polarizations p . The other parameters are the same as in Fig. 1.

$p = 0.8$ and $p = 1$ in Fig. 2(a), the peak-splitting disappears, as can be understood from the fact that the spin-flip process can hardly ($p = 0.8$) or fully not ($p = 1$) occur in these specific cases, thus no additional channel is opened for ET even when $V \geq \Delta$, in comparison with smaller polarization $p < 0.8$ ¹². For the case of vanishing spin-splitting $\Delta = 0$, the linear conductance $G_P^0 = \frac{dI_P}{dV}|_{V \rightarrow 0}$, is readily given by

$$G_P^0/\pi g = 4. \quad (17)$$

On the contrary, for the AP configuration, a ZBP emerges. Obviously, this behavior stems mathematically from the sharp peak in $\frac{\partial S^z}{\partial V}$ around $V = 0$ [Fig. 1(a)] according to Eq. (12a). Consequently, one can conclude that the underlying rapid spin-reversal due to *spin-flip elastic* cotunneling is responsible for the novel ZBP from a physical point of view. With the help of Eq. (7), we obtain the linear conductance, $G_{AP}^0 = \frac{dI_{AP}}{dV}|_{V \rightarrow 0}$, as

$$G_{AP}^0/\pi g = 3 + p^2 - 16Tp \frac{\partial S_{AP}^z}{\partial V} \Big|_{V \rightarrow 0} = 4(1 - p^2). \quad (18)$$

We can also calculate the differential conductance G_{AP} at the limit of $V/T \rightarrow \infty$:

$$G_{AP}^\infty/\pi g = 3 + p^2 - 8pS_{AP}^z|_{V \rightarrow \infty} = \frac{4(1 - p^2)}{1 + p^2}. \quad (19)$$

It is easy to see that $G_{AP}^0 > G_{AP}^\infty$ is always satisfied, which reflects the ZBP. Moreover, the relative height x of the ZBP is defined as

$$x = \frac{G_{AP}^0 - G_{AP}^\infty}{G_{AP}^\infty} = p^2, \quad (20)$$

which is exactly the same as the result in Ref. 9. Furthermore, we examine the temperature dependence of the ZBP as shown in Fig. 3(b). It is found that increasing temperature will enhance the width of the ZBP, but reduce the peak height a bit, which is qualitatively consistent with the numerical calculations in Ref. 9 [see their Fig. 1(b)]. Interestingly, the novel ZBP in the AP configuration is robust over a rather wide region of temperature. It is worth emphasizing that our investigation is valid for the cotunneling through a strongly Coulomb-blockaded QD ($U \rightarrow \infty$) in the weak-tunneling limit, thus the contribution of the charge fluctuation effect is completely excluded in the present analysis. We believe that this is the reason for the difference between our analysis and the numerical calculations of Ref. 9.

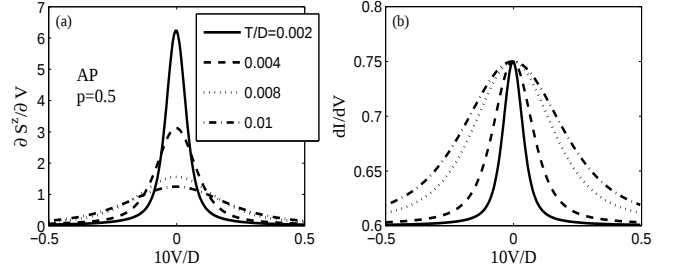


FIG. 3: Temperature dependences of $\frac{\partial S^z}{\partial V}$ (a) and differential conductance (b) as functions of bias-voltage in the AP configuration with zero magnetic field and $p = 0.5$.

In combination with the peak-splitting in the P configuration, the ZBP in the AP configuration will cause a deep dip in TMR at $V = 0$, as shown in Fig. 2(c). Analogously, an ambient magnetic field leads to peak-splitting since *inelastic spin-flip* cotunneling requires sufficient energy for activation. Contrary to the P alignment case, the two peaks in $\frac{dI_{AP}}{dV}$ have unequal heights due in part to the asymmetry in $\frac{\partial S^z}{\partial V}$ with nonzero Δ_Z [Fig. 1(b)]. Correspondingly, the magnetic field changes the behavior of TMR [Fig. 2(f)].

Richly detailed structures are observed in the differential zero-frequency shot noise, $\frac{dS}{dV}$, as shown in Fig. 4. Differing from the differential conductance, the resulting QD spin-splitting causes an additional step structure in $\frac{dS}{dV}$ with equal (P) and unequal (AP) heights [Fig. 4(a), (c), and (d)]. Simple algebraic calculation gives:

$$\frac{dS^P}{dV} \Big|_{V \rightarrow 0} = \frac{dS^{AP}}{dV} \Big|_{V \rightarrow 0} = 0, \quad (21)$$

$$\frac{dS^P}{dV} \Big|_{V \rightarrow \infty} = 4 > 0, \quad (22)$$

$$\frac{dS^{AP}}{dV} \Big|_{V \rightarrow \infty} = \frac{4(1 - p^2)}{1 + p^2} \geq 0, \quad (23)$$

at $\Delta = 0$. Generally, the zero-frequency shot noise will always increase with increasing bias-voltage. However, a contrary phenomenon is predicted in our calculation for the case of the AP alignment leads with large polarization

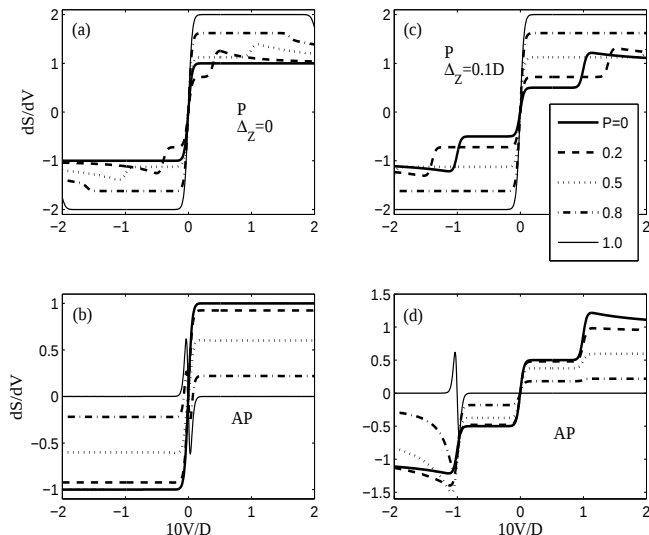


FIG. 4: Differential zero-frequency shot noise as a function of bias-voltage with zero (a), (b) and nonzero (c), (d) external magnetic fields for various polarizations p . The other parameters are the same as in Fig. 1.

p : the differential shot noise changes sign near $V = -\Delta$. This behavior can also be ascribed to the rather sharp peak in $\frac{\partial S^z}{\partial V}$ due to large p , i.e. to rapid QD spin-reversal. In Fig. 5, we also examine the temperature dependence of the differential shot noise at $\Delta = 0$. It is seen that this behavior is more pronounced for higher temperature

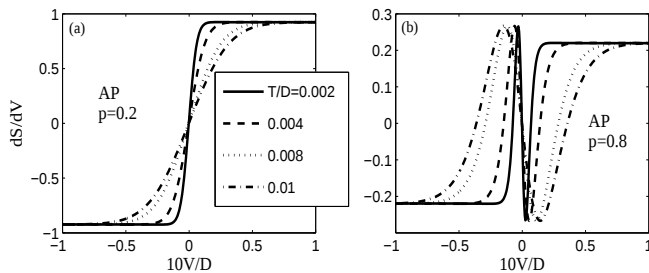


FIG. 5: Temperature dependencies of differential shot noise as functions of bias-voltage in the AP configuration without external magnetic field for $p = 0.2$ (a) and $p = 0.8$ (b).

V. CONCLUSIONS

In summary, we have applied a quantum Langevin equation approach to derive a Bloch-type equation microscopically for analytical studies of inelastic cotunneling, which we have carried out in detail, determining the local magnetization, current and its fluctuations, in a single QD attached to two ferromagnetic electrodes. Our studies reveal a number of interesting novel characteristics intimately related to *spin-flip* processes in the AP configuration: 1) a ZBP of the differential conductance at zero external magnetic field; 2) asymmetric peak-splitting in the presence of a nonzero magnetic field; and 3) decreasing shot noise near $V = -\Delta$. In addition, we have found that these characteristics are robust against temperature.

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 - ¹⁹ We took no account of the contribution of the direct tunneling term in our previous paper, Ref. 12. If this term is included, the linearly bias-voltage relevant term in the charge current formula, Eq. (36), becomes $4V$ in stead of $3V$.